

# **1 Lecture 1b: DFM For Dummies**

## **1.1 @luk036**

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## **1.2 Abstract**

DFM is an engineering practice that optimizes the manufacturing ease and production cost of ICs while meeting performance, power, and reliability requirements. As ICs become more miniaturized and complex, the manufacturing process becomes sensitive to variations and defects, which can degrade chip quality and functionality. DFM helps address various manufacturing issues. DFM can be applied to various aspects of IC design, such as circuit design, logic design, layout design, verification, and testing. The lecture covers the general guidelines and best practices of DFM for layout design. Applying DFM techniques in the physical design stage of IC development can help reduce the number of design iterations, improve collaboration with foundries, enhance product performance and functionality, and achieve faster time-to-market and lower production costs. The lecture discusses the challenges of DFM and its market share, including DFM analysis and verification, enhancement, optimization, and the algorithms that solve DFM problems. The course structure highlights the problems that arise from DFM and abstracts them into mathematical forms.

## **1.3 Faster, smaller & smarter**

## **1.4 Silicon Gold Rush?**

## **1.5 Current Transistors**

- High-K dielectrics, Metal Gate (HKMG)
- “3D” gate

The significance of High-K dielectrics is that they have a higher dielectric constant than traditional silicon dioxide (SiO<sub>2</sub>) dielectrics. This allows for a thicker gate oxide layer to be used without increasing the gate capacitance,



图 1: iPhoneX



图 2: SMIC

which can improve the transistor's performance and reduce leakage current.

Metal Gate refers to the use of a metal material (such as tungsten or tantalum) for the gate electrode, instead of the traditional polysilicon material. This is significant because metal gates can provide better control over the transistor's threshold voltage, which can improve its performance and reduce variability.

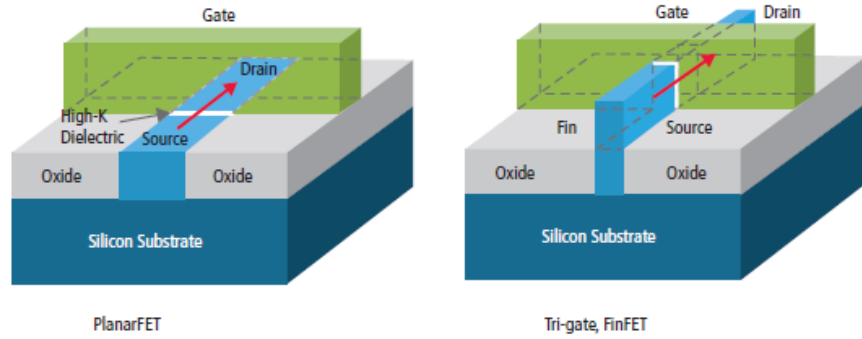


图 3: FinFET

## 1.6 Lithography

- Photo-resist coating
- Illumination
- Exposure
- Etching
- Impurities Doping
- Metal connection

## 1.7 Process-Design Gap

## 1.8 Problem Visualization

One of the main impacts of lithography is that it can cause variations in the dimensions and shapes of the IC's features, which can negatively impact the performance and yield of the IC. This is because lithography is a complex process that involves the use of light to transfer a pattern from a mask to

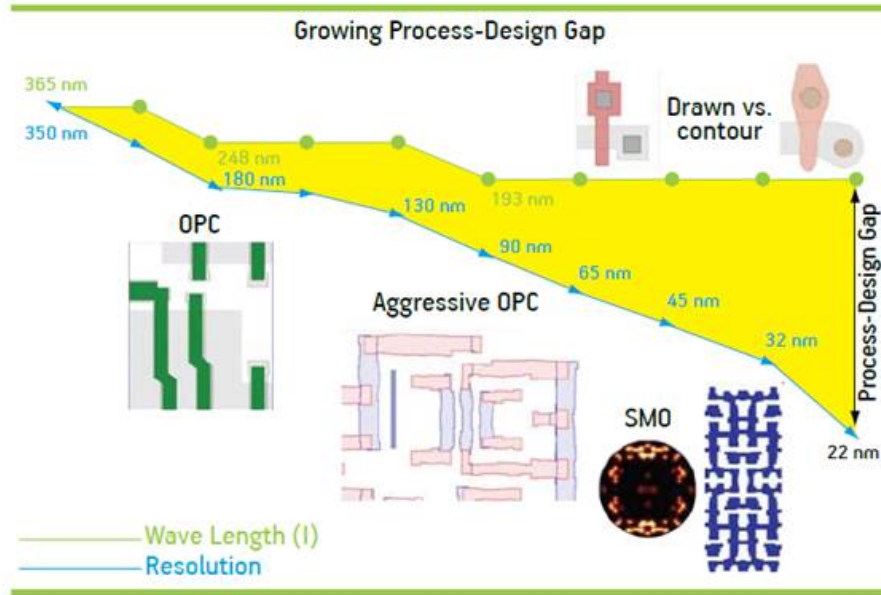


图 4: Process-Design Gap

a wafer. Variations in the intensity, wavelength, and angle of the light can cause deviations in the dimensions and shapes of the features, which can lead to process-induced variation.

## 1.9 Chemical Mechanical Polishing

Chemical Mechanical Polishing (CMP) is a process used in semiconductor manufacturing to planarize the surface of a wafer. CMP is one of the steps involved in the fabrication of integrated circuits, specifically in the metal connection stage.

## 1.10 Chemical Mechanical Polishing

In terms of bridging the Process-Design Gap, CMP can help address the issue of process-induced variation by improving the uniformity of the wafer surface. This is important because process-induced variation can cause deviations in the dimensions and electrical properties of the transistors, which

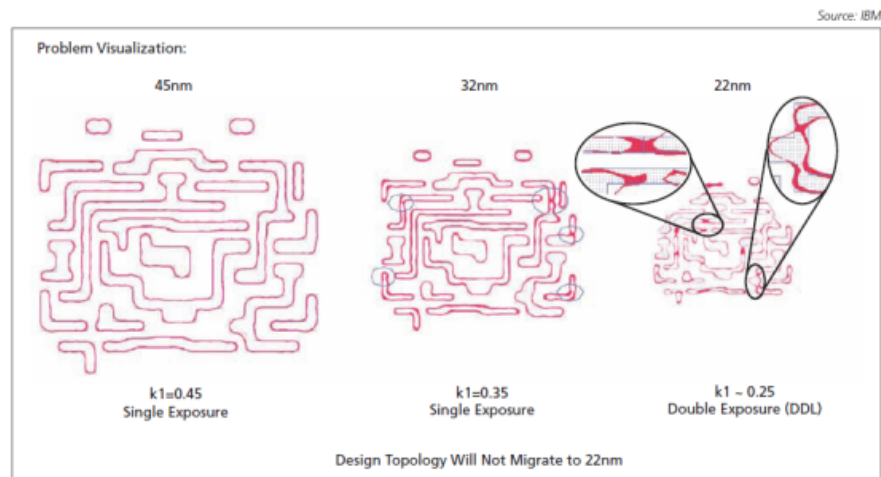


图 5: ibm

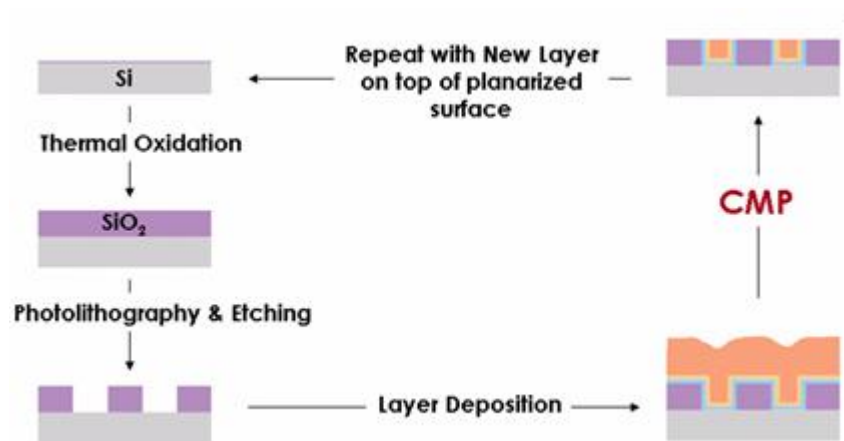


图 6: CMP

can negatively impact the performance and yield of the IC.

### 1.11 ECP & CMP

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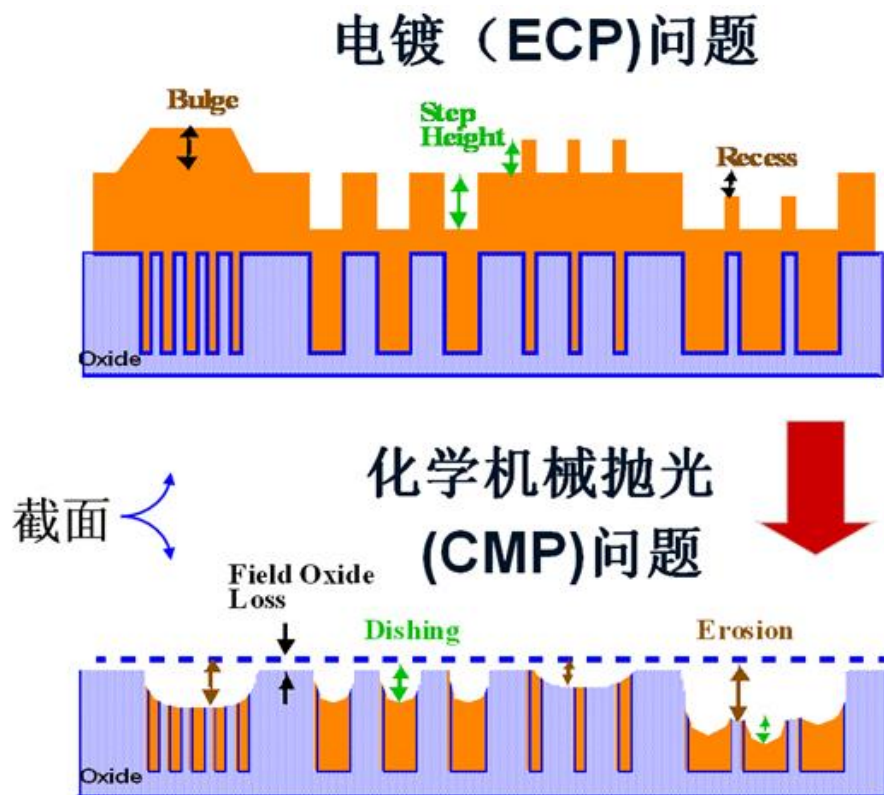


图 7: ECP

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By using CMP to planarize the wafer surface, designers can reduce the variability in the thickness of the metal layers, which can improve the accuracy and consistency of the IC's electrical properties. This, in turn, can help bridge the Process-Design Gap by ensuring that the ICs are manufactured according to the intended design specifications.

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## 2 Process Variation

### 2.1 Total Thickness Variation Per Node

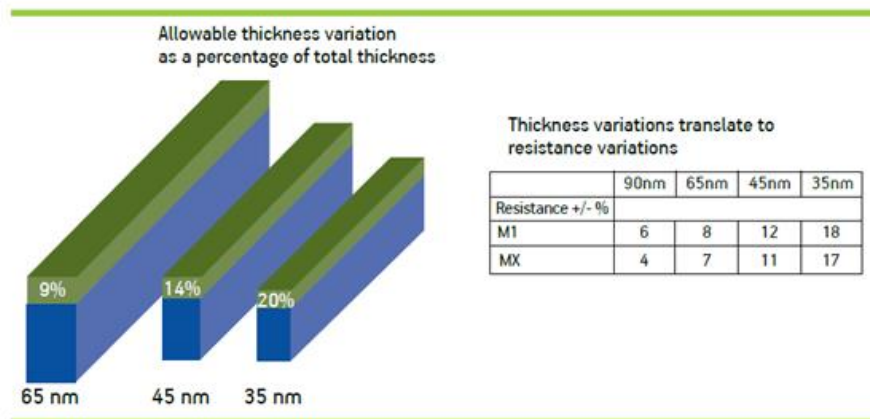


图 8: Thickness Variation

### 2.2 “Slippery Fish” at 45nm

- Process variation, impacting yield and performance
- More restricted design rules (RDRs)
  - +3 or more rules at 45nm
  - +100 or more rules at 32nm
  - +250 or more rules at 22nm
- More rules implies larger die size, lower performance
- 10nm is not sci-fiction due to FinFET technology

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## 3 DFM

### 3.1 What is DFM?

- Design for ?
- Design for Manufacturing
- Design for Manufacturability
  - Refer to a group of challenges less than 130nm
  - The engineering practice of designing integrated circuits (ICs) to optimize their manufacturing ease and production cost given performance, power and reliability requirements
  - A set of techniques to modify the design of ICs to improve their functional yield, parametric yield or their reliability

### 3.2 Why is it important?

- Achieving high-yielding designs in the state-of-the-art VLSI technology is extremely challenging due to the miniaturization and complexity of leading-edge products
- The manufacturing process becomes more sensitive to variations and defects, which can degrade the quality and functionality of the chips
- DFM can help to address various manufacturing issues, such as lithography hotspots, CMP dishing and erosion, antenna effects, electromigration, stress effects, layout-dependent effects and more

### 3.3 How is it applied?

- DFM can be applied to various aspects of IC design, such as circuit design, logic design, layout design, verification and testing
- Each aspect has its own specific DFM guidelines and best practices that designers should follow to ensure manufacturability
- For example, some general DFM guidelines for layout design are:
  - Use regular and uniform layout structures
  - Avoid narrow or long metal wires
  - Avoid acute angles or jogs in wires



- Avoid isolated or floating features
- Use dummy fill to improve planarity and density uniformity
- Use recommended design rules and constraints from foundries

### 3.4 What are the benefits?

- By applying DFM techniques in the physical design stage of IC development, designers can:
  - Reduce the number of design iterations
  - Improve the collaboration with foundries
  - Enhance the product performance and functionality
  - Achieve faster time to market and lower production costs

### 3.5 DFM Market Share 2008

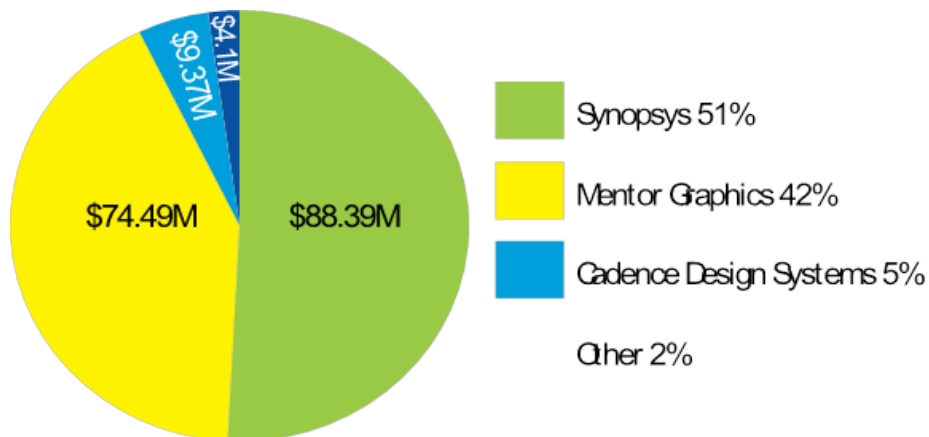


图 9: Market Share

### 3.6 DFM Forecast 2009 in \$M

### 3.7 Increasing Importance of DFM

### 3.8 DFM Analysis and Verification

- Critical area analysis
- CMP modeling

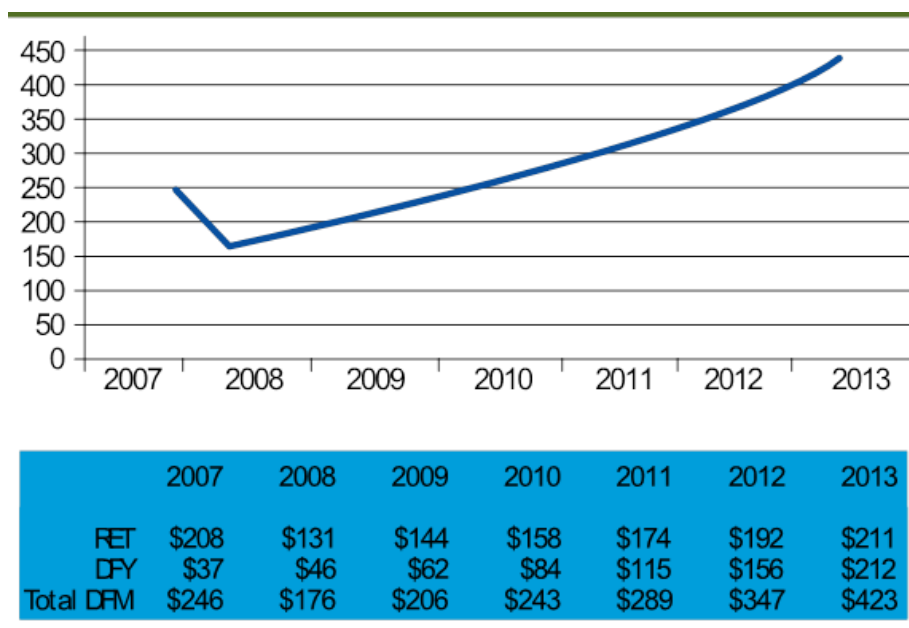


图 10: forecast

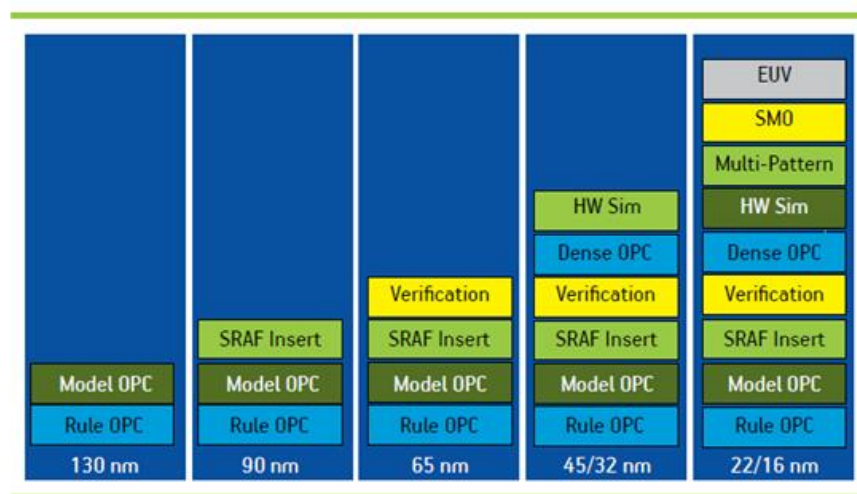


图 11: trend

- Statistical timing analysis
- Pattern matching
- Lithography simulation
- Lithographic hotspot verification

### 3.9 2D Pattern Matching in DRC+

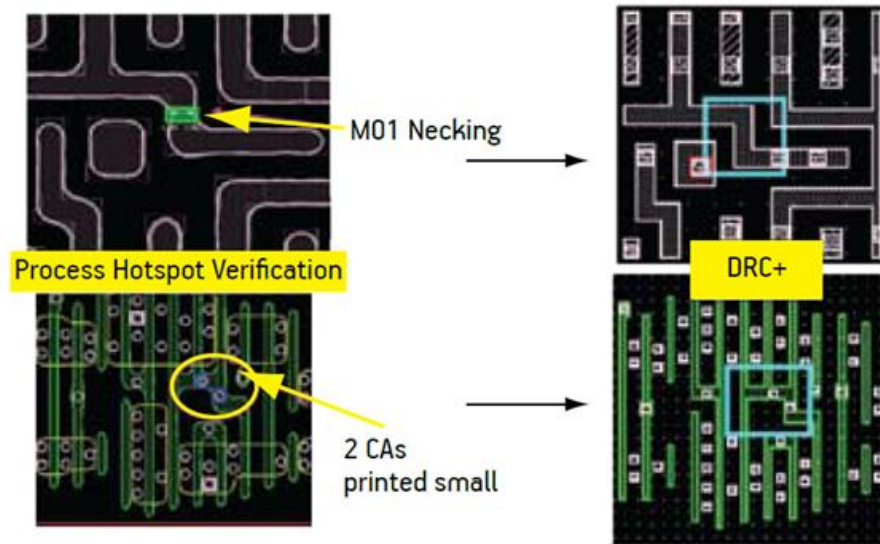


图 12: DRC+

### 3.10 Contour Based Extraction

### 3.11 DFM Enhancement and Optimization

- Wire spreading
- Dummy Filling
- Redundant Via Insertion
- Optical proximity correlation (OPC)
- Phase Shift Masking (PSM)
- Double/Triple/Multiple Patterning
- Statistical timing and power optimization

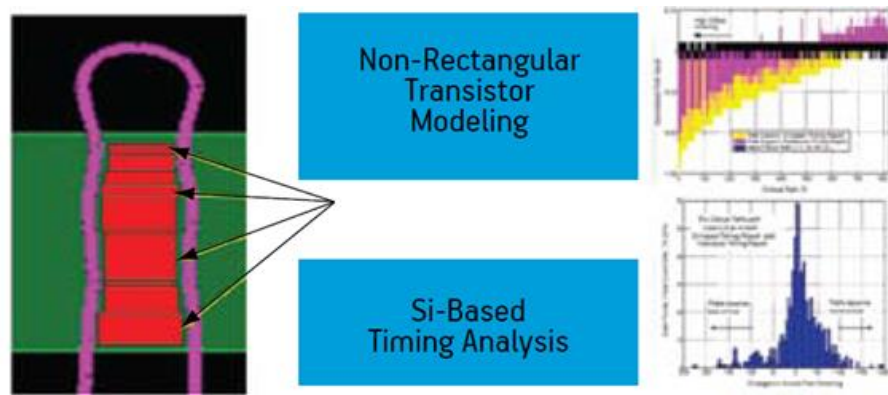


图 13: contour

### 3.12 Dummy Filling



图 14: filling

### 3.13 “Smart” Filling

### 3.14 Redundant Via Insertion

- Also known as double via insertion.
- Post-routing RVI (many EDA tools already have this feature)
- Considering RVI during routing

???

Looks good, right?

But actually only few people are using this!

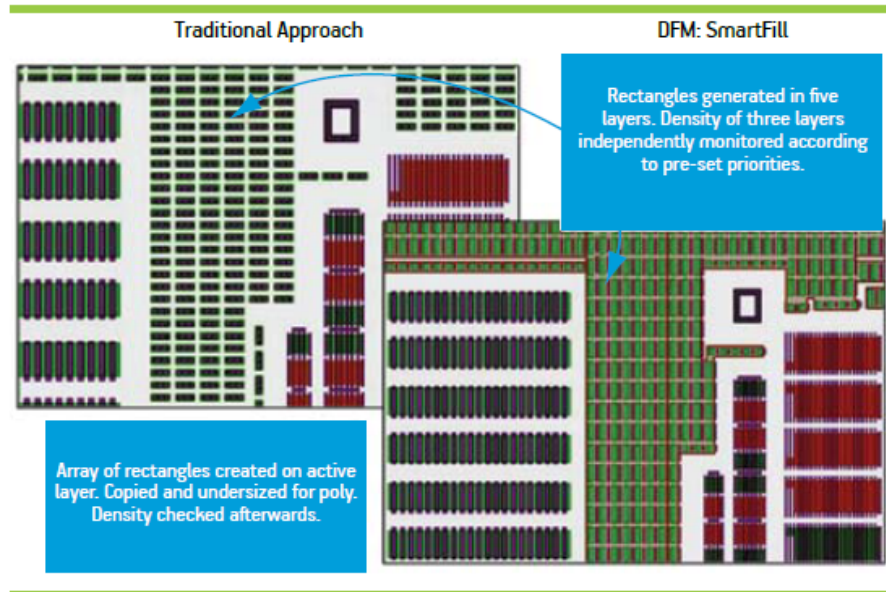


图 15: “Smart” Filling

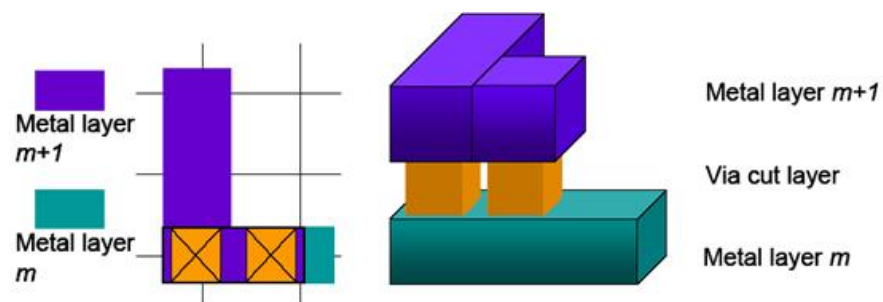


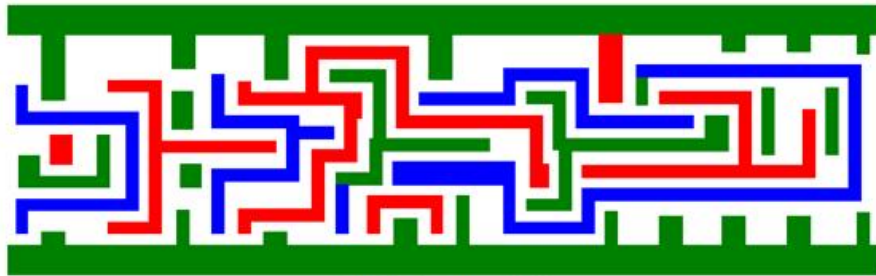
Fig. 1 Illustration for redundant via insertion.

图 16: RVI

Why?

### 3.15 Multiple Patterning (MPL)

- Instead of exposing the photoresist layer once under one mask, MPL exposes it twice by splitting the mask into “k” parts, each with features less dense.



(b) Triple patterning

图 17: MPL

### 3.16 What are the challenges of DFM?

- DFM is not a fixed set of rules, but rather a flexible and evolving methodology that depends on the product requirements, the manufacturing technology and the industry standards
- DFM can also be combined with other design methodologies, such as DFT, DFR, DFLP and DFS, to create a holistic approach to product development
- DFM requires strong capabilities in research, supply chain, talent, IP protection and government policies

### 3.17 Course Structure

- Describe the DFM problems that arise from.
- Abstract the problems in mathematical forms
- Describe the algorithms that solve the problems
- Discuss the alternative algorithms and possible improvement.

- Discuss if the algorithms can be applied to other area.
- Only describe the key idea in lectures. Details are left for paper reading if necessary.

### **3.18 Not covered**

- Algorithms for 3D problems
- Packaging
- Machine Learning/AI Based algorithm